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Kind regards,

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# PMP5201V; PMP5201G; PMP5201Y

**PNP/PNP** matched double transistors

Rev. 03 — 28 August 2009

**Product data sheet** 

## 1. Product profile

## 1.1 General description

PNP/PNP matched double transistors in small Surface-Mounted Device (SMD) plastic packages. The transistors in the SOT666 and SOT363 (SC-88) packages are fully isolated internally.

Table 1. Product overview

Type number	Package		PNP/PNP h <sub>FE1</sub> /h <sub>FE2</sub>	NPN/NPN	
	NXP JEITA 0.95 complement		0.95 complement	complement	
PMP5201V	SOT666	-	PMP5501V	PMP4201V	
PMP5201G	SOT353	SC-88A	PMP5501G	PMP4201G	
PMP5201Y	SOT363	SC-88	PMP5501Y	PMP4201Y	

#### 1.2 Features

- Current gain matching
- Base-emitter voltage matching
- Common emitter configuration for SOT353 types
- Application-optimized pinout

## 1.3 Applications

- Current mirror
- Differential amplifier

## 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transis	stor					
$V_{CEO}$	collector-emitter voltage	open base	-	-	-45	V
I <sub>C</sub>	collector current		-	-	-100	mA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V};$ $I_{C} = -2 \text{ mA}$	200	290	450	



# PMP5201V; PMP5201G; PMP5201Y

## **PNP/PNP** matched double transistors

Table 2. Quick reference data ... continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device						
h <sub>FE1</sub> /h <sub>FE2</sub>	h <sub>FE</sub> matching	$V_{CE} = -5 \text{ V};$ $I_C = -2 \text{ mA}$	[1] 0.98	1	-	
$V_{BE1}-V_{BE2}$	V <sub>BE</sub> matching	$V_{CE} = -5 \text{ V};$ $I_C = -2 \text{ mA}$	[2] _	-	2	mV

<sup>[1]</sup> The smaller of the two values is taken as the numerator.

#### **Pinning information** 2.

Table 2 Dinning

Pin	Description	Simplified outline	Symbol		
SOT666;	SOT363				
1	base TR1				
2	base TR2	6 5 4	6 5 4		
3	collector TR2		TR1 TR2		
4	emitter TR2				
5	emitter TR1		1 2 3 006aaa550		
6	collector TR1	001aab555			
SOT353					
1	base TR1	П- П.			
2	emitter TR1, TR2	5	5 4		
3	base TR2		TR1 TR2		
4	collector TR2				
5	collector TR1	<u> </u> 1   2   3	1 2 3 006aaa551		

#### **Ordering information** 3.

Table 4. **Ordering information** 

Type number	Package		
	Name	Description	Version
PMP5201V	<b>-</b>	plastic surface-mounted package; 6 leads	SOT666
PMP5201G	SC-88A	plastic surface-mounted package; 5 leads	SOT353
PMP5201Y	SC-88	plastic surface-mounted package; 6 leads	SOT363

<sup>[2]</sup> The smaller of the two values is subtracted from the larger value.

## 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
PMP5201V	EC
PMP5201G	R5*
PMP5201Y	S9*

<sup>[1] \* = -:</sup> made in Hong Kong

## 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor				
$V_{CBO}$	collector-base voltage	open emitter	-	-50	V
$V_{CEO}$	collector-emitter voltage	open base	-	-45	V
$V_{EBO}$	emitter-base voltage	open collector	-	-5	V
I <sub>C</sub>	collector current		-	-100	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	SOT666		[1][2]	200	mW
	SOT353		[1] _	200	mW
	SOT363		<u>[1]</u> _	200	mW
Per device	•				
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	SOT666		[1][2]	300	mW
	SOT353		[1] _	300	mW
	SOT363		<u>[1]</u> -	300	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

## 6. Thermal characteristics

Table 7. Thermal characteristics

Table 1.	Thermal characteristics					
Symbol	Parameter	Conditions	Mir	т Тур	Max	Unit
Per trans	istor					
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air				
	SOT666		[1][2]	-	625	K/W
	SOT353		<u>[1]</u> _	-	625	K/W
	SOT363		<u>[1]</u> _	-	625	K/W
Per devic	e					
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	SOT666		[1][2]	-	416	K/W
	SOT353		<u>[1]</u> _	-	416	K/W
	SOT363		<u>[1]</u> _	-	416	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

## 7. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
Per transistor								
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -30 \text{ V};$ $I_E = 0 \text{ A}$	-	-	<b>–15</b>	nA		
		$V_{CB} = -30 \text{ V};$ $I_{E} = 0 \text{ A};$ $T_{j} = 150 \text{ °C}$	-	-	<b>-</b> 5	μΑ		
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V};$ $I_{C} = 0 \text{ A}$	-	-	-100	nA		
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V};$ $I_{C} = -10 \mu\text{A}$	-	250	-			
		$V_{CE} = -5 \text{ V};$ $I_C = -2 \text{ mA}$	200	290	450			
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -10 \text{ mA};$ $I_B = -0.5 \text{ mA}$	-	-50	-200	mV		
		$I_C = -100 \text{ mA};$ $I_B = -5 \text{ mA}$	-	-200	-400	mV		
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C = -10 \text{ mA};$ $I_B = -0.5 \text{ mA}$	[1] -	-760	-	mV		
		$I_{C} = -100 \text{ mA};$ $I_{B} = -5 \text{ mA}$	[1] -	-920	-	mV		

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

Characteristics ...continued Table 8.  $T_{amb}$  = 25 °C unless otherwise specified.

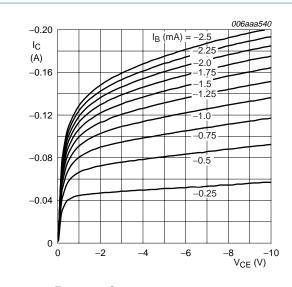
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{BE}$	base-emitter voltage	$V_{CE} = -5 \text{ V};$ $I_C = -2 \text{ mA}$	<u>[2]</u> –600	-650	-700	mV
		$V_{CE} = -5 \text{ V};$ $I_C = -10 \text{ mA}$	[2] -	-	-760	mV
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V};$ $I_E = i_e = 0 \text{ A};$ $f = 1 \text{ MHz}$	-	-	2.2	pF
C <sub>e</sub>	emitter capacitance	$V_{EB} = -0.5 \text{ V};$ $I_{C} = i_{c} = 0 \text{ A};$ $f = 1 \text{ MHz}$	-	10	-	pF
f <sub>⊤</sub>	transition frequency	$V_{CE} = -5 \text{ V};$ $I_{C} = -10 \text{ mA};$ $f = 100 \text{ MHz}$	100	175	-	MHz
NF	noise figure	$V_{CE} = -5 \text{ V};$ $I_{C} = -0.2 \text{ mA};$ $R_{S} = 2 \text{ k}\Omega;$ $f = 10 \text{ Hz to}$ 15.7 kHz	-	1.6	-	dB
		$V_{CE} = -5 \text{ V};$ $I_{C} = -0.2 \text{ mA};$ $R_{S} = 2 \text{ k}\Omega;$ $f = 1 \text{ kHz};$ $B = 200 \text{ Hz}$	-	3.1	-	dB
Per device						
h <sub>FE1</sub> /h <sub>FE2</sub>	h <sub>FE</sub> matching	$V_{CE} = -5 \text{ V};$ $I_C = -2 \text{ mA}$	<u>3</u> 0.98	1	-	
$V_{BE1}-V_{BE2}$	V <sub>BE</sub> matching	$V_{CE} = -5 \text{ V};$ $I_C = -2 \text{ mA}$	<u>[4]</u> -	-	2	mV

<sup>[1]</sup>  $V_{BEsat}$  decreases by about 1.7 mV/K with increasing temperature.

<sup>[2]</sup> V<sub>BE</sub> decreases by about 2 mV/K with increasing temperature.

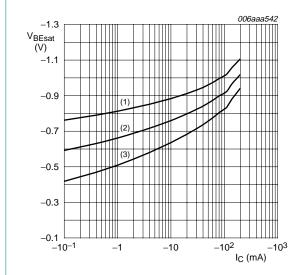
<sup>[3]</sup> The smaller of the two values is taken as the numerator.

<sup>[4]</sup> The smaller of the two values is subtracted from the larger value.



 $T_{amb} = 25 \, ^{\circ}C$ 

Fig 1. Collector current as a function of collector-emitter voltage; typical values



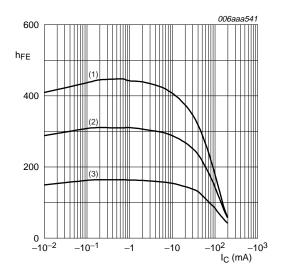
 $I_{\rm C}/I_{\rm B}=20$ 

(1)  $T_{amb} = -55 \,^{\circ}C$ 

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig 3. Base-emitter saturation voltage as a function of collector current; typical values



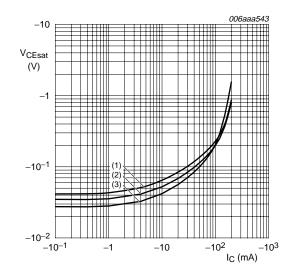
 $V_{CE} = -5 \text{ V}$ 

(1)  $T_{amb} = 100 \, ^{\circ}C$ 

(2)  $T_{amb} = 25 \,^{\circ}C$ 

(3)  $T_{amb} = -55 \, ^{\circ}C$ 

Fig 2. DC current gain as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 20$ 

(1)  $T_{amb} = 100 \, ^{\circ}C$ 

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = -55 \, ^{\circ}C$ 

Fig 4. Collector-emitter saturation voltage as a function of collector current; typical values

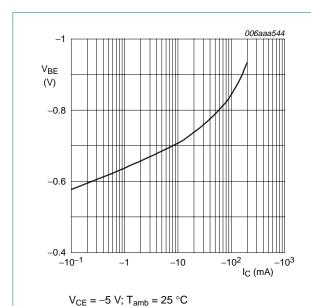


Fig 5. Base-emitter voltage as a function of collector current; typical values

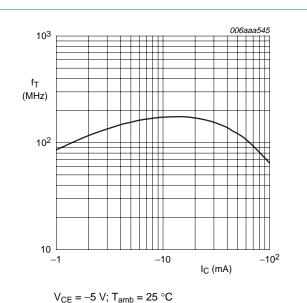


Fig 6. Transition frequency as a function of collector current; typical values

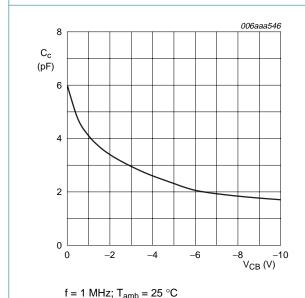


Fig 7. Collector capacitance as a function of collector-base voltage; typical values

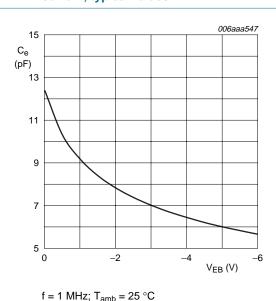
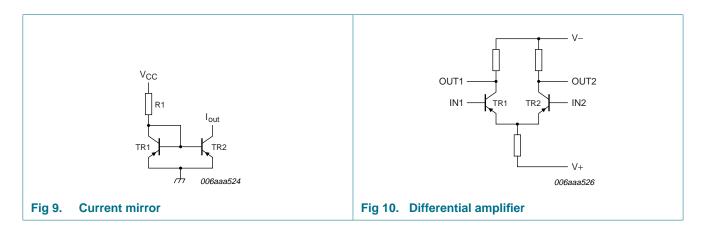
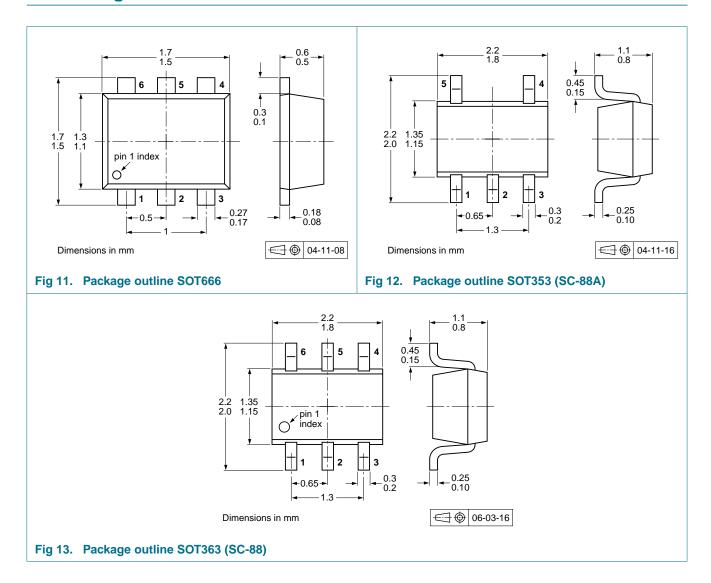


Fig 8. Emitter capacitance as a function of emitter-base voltage; typical values

## 8. Application information



## 9. Package outline



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## 10. Packing information

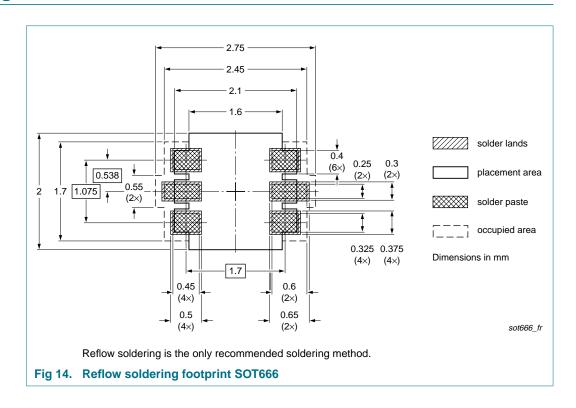
Table 9. Packing methods

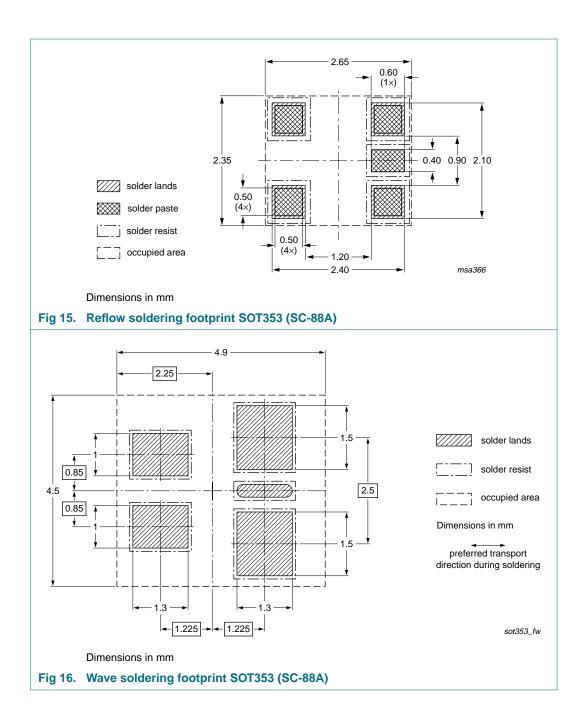
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

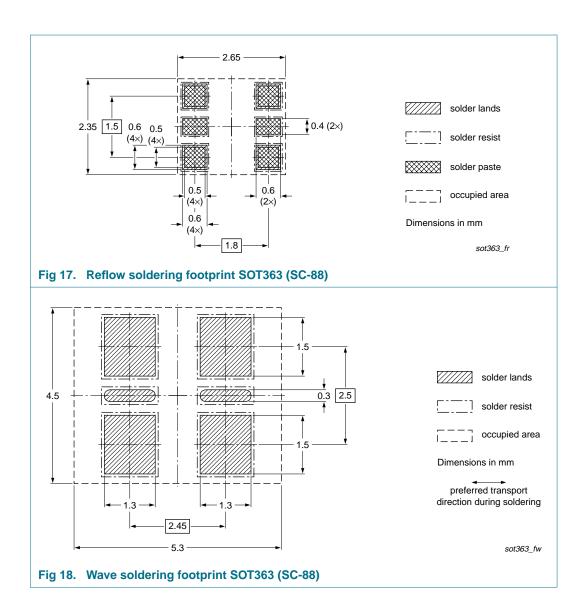
Type number	Package	age Description		Packing quantity			
				3000	4000	8000	10000
PMP5201V	SOT666	2 mm pitch, 8 mm tape and reel		-	-	-315	-
		4 mm pitch, 8 mm tape and reel		-	-115	-	-
PMP5201G	SOT353	4 mm pitch, 8 mm tape and reel		-115	-	-	-135
PMP5201Y	SOT363	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-	-	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-	-	-165

- [1] For further information and the availability of packing methods, see Section 14.
- [2] T1: normal taping
- [3] T2: reverse taping

## 11. Soldering







## 12. Revision history

## Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
PMP5201V_G_Y_3	20090828	Product data sheet	-	PMP5201V_G_Y_2			
Modifications:	<ul> <li>This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content.</li> </ul>						
	• Figure 14 "R	eflow soldering footprint SOT6	66": updated				
	<ul><li>Figure 16 "W</li></ul>	ave soldering footprint SOT35	3 (SC-88A)": update	d			
	• Figure 17 "R	eflow soldering footprint SOT3	63 (SC-88)": update	d			
	• Figure 18 "W	ave soldering footprint SOT36	3 (SC-88)": updated				
PMP5201V_G_Y_2	20060914	Product data sheet	-	PMP5201G_Y_1			
PMP5201G_Y_1	20060214	Product data sheet	-	-			

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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13 of 14

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# PMP5201V; PMP5201G; PMP5201Y

## **NXP Semiconductors**

#### **PNP/PNP** matched double transistors

## 15. Contents

1	Product profile	1
1.1	General description	1
1.2	Features	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Marking	3
5	Limiting values	3
6	Thermal characteristics	4
7	Characteristics	4
8	Application information	8
9	Package outline	8
10	Packing information	9
11	Soldering	9
12	Revision history	2
13	Legal information1	3
13.1	Data sheet status	3
13.2	Definitions	3
13.3	Disclaimers	3
13.4	Trademarks1	3
14	Contact information	3
15	Contents 1	4

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